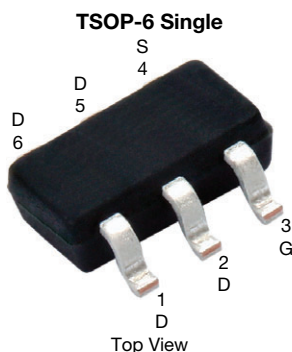


P-Channel 12 V (D-S) MOSFET



Marking code: BB

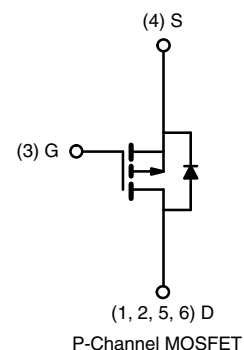
PRODUCT SUMMARY	
V_{DS} (V)	-12
$R_{DS(on)}$ max. (Ω) at $V_{GS} = -4.5$ V	0.0175
$R_{DS(on)}$ max. (Ω) at $V_{GS} = -2.5$ V	0.0230
$R_{DS(on)}$ max. (Ω) at $V_{GS} = -1.8$ V	0.0330
Q_g typ. (nC)	28.3
I_D (A) ^a	-8
Configuration	Single

FEATURES

- TrenchFET® power MOSFET
- PWM optimized
- 100 % R_g tested
- Material categorization:
for definitions of compliance please see
www.vishay.com/doc?99912

APPLICATIONS

- Load switch
- DC/DC converters


RoHS
COMPLIANT
HALOGEN
FREE


ORDERING INFORMATION	
Package	TSOP-6
Lead (Pb)-free and halogen-free	Si3477DV-T1-GE3

ABSOLUTE MAXIMUM RATINGS ($T_A = 25$ °C, unless otherwise noted)				
PARAMETER	SYMBOL	LIMIT	UNIT	
Drain-source voltage	V_{DS}	-12	V	
Gate-source voltage	V_{GS}	± 10		
Continuous drain current ($T_J = 150$ °C)	$T_C = 25$ °C	-8 ^a	A	
	$T_C = 70$ °C	-8 ^a		
	$T_A = 25$ °C	-8 ^{a, b, c}		
	$T_A = 70$ °C	-7.2 ^{b, c}		
Pulsed drain current	I_{DM}	-40		
Continuous source-drain diode current	$T_C = 25$ °C	-3.5		
	$T_A = 25$ °C	-1.67 ^{b, c}		
Maximum power dissipation	$T_C = 25$ °C	4.2	W	
	$T_C = 70$ °C	2.7		
	$T_A = 25$ °C	2 ^{b, c}		
	$T_A = 70$ °C	1.3 ^{b, c}		
Operating junction and storage temperature range	T_J, T_{stg}	-55 to +150	°C	

THERMAL RESISTANCE RATINGS					
PARAMETER	SYMBOL	TYPICAL	MAXIMUM	UNIT	
Maximum junction-to-ambient ^{b, d}	$t \leq 5$ s	R_{thJA}	50	62.5	°C/W
Maximum junction-to-foot (drain)	Steady state	R_{thJF}	22	30	

Notes

- Package limited
- Surface mounted on 1" x 1" FR4 board
- $t = 5$ s
- Maximum under steady state conditions is 110 °C/W



SPECIFICATIONS (T _J = 25 °C, unless otherwise noted)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT	
Static							
Drain-source breakdown voltage	V _{DS}	V _{GS} = 0 V, I _D = -250 μA	-12	-	-	V	
V _{DS} temperature coefficient	ΔV _{DS} /T _J	I _D = 250 μA	-	-4.1	-	mV/°C	
V _{GS(th)} temperature coefficient	ΔV _{GS(th)} /T _J		-	2.5	-		
Gate-source threshold voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = -250 μA	-0.4	-	-1	V	
Gate-source leakage	I _{GSS}	V _{DS} = 0 V, V _{GS} = ± 10 V	-	-	± 100	nA	
Zero gate voltage drain current	I _{DSS}	V _{DS} = -12 V, V _{GS} = 0 V	-	-	-1	μA	
		V _{DS} = -12 V, V _{GS} = 0 V, T _J = 85 °C	-	-	-10		
On-state drain current ^a	I _{D(on)}	V _{DS} ≤ -5 V, V _{GS} = -4.5 V	-20	-	-	A	
Drain-source on-state resistance ^a	R _{DS(on)}	V _{GS} = -4.5 V, I _D = -9 A	-	0.0140	0.0175	Ω	
		V _{GS} = -2.5 V, I _D = -7.9 A	-	0.0190	0.0230		
		V _{GS} = -1.8 V, I _D = -2.2 A	-	0.0260	0.0330		
Forward transconductance ^a	g _{fs}	V _{DS} = -6 V, I _D = -9 A	-	30	-	S	
Dynamic ^b							
Input capacitance	C _{iss}	V _{DS} = -6 V, V _{GS} = 0 V, f = 1 MHz	-	2600	-	pF	
Output capacitance	C _{oss}		-	620	-		
Reverse transfer capacitance	C _{rss}		-	625	-		
Total gate charge	Q _g	V _{DS} = -6 V, V _{GS} = -10 V, I _D = -9 A	-	58	90	nC	
Gate-source charge	Q _{gs}	V _{DS} = -6 V, V _{GS} = -4.5 V, I _D = -9 A	-	28.3	45		
Gate-drain charge	Q _{gd}		-	4.2	-		
Gate resistance	R _g		-	7.8	-		
Turn-on delay time	t _{d(on)}	f = 1 MHz	0.9	4.5	9	Ω	
Rise time	t _r		V _{DD} = -6 V, R _L = 0.83 Ω I _D ≅ -7.2 A, V _{GEN} = -4.5 V, R _g = 1 Ω	-	25	40	ns
Turn-off delay time	t _{d(off)}			-	30	45	
Fall time	t _f			-	65	100	
Turn-on delay time	t _{d(on)}	V _{DD} = -6 V, R _L = 0.83 Ω I _D ≅ -7.2 A, V _{GEN} = -10 V, R _g = 1 Ω		-	35	55	
Turn-on delay time	t _{d(on)}		-	10	15		
Rise time	t _r		-	10	15		
Turn-off delay time	t _{d(off)}		-	65	100		
Fall time	t _f		-	30	45		
Drain-Source Body Diode Characteristics							
Continuous source-drain diode current	I _S	T _C = 25 °C	-	-	-3.5	A	
Pulse diode forward current ^a	I _{SM}		-	-	-40		
Body diode voltage	V _{SD}	I _S = -7.2 A	-	-0.8	-1.2	V	
Body diode reverse recovery time	t _{rr}	I _F = -7.2 A, di/dt = 100 A/μs, T _J = 25 °C	-	50	75	ns	
Body diode reverse recovery charge	Q _{rr}		-	30	45	nC	
Reverse recovery fall time	t _a		-	21	-	ns	
Reverse recovery rise time	t _b		-	29	-		

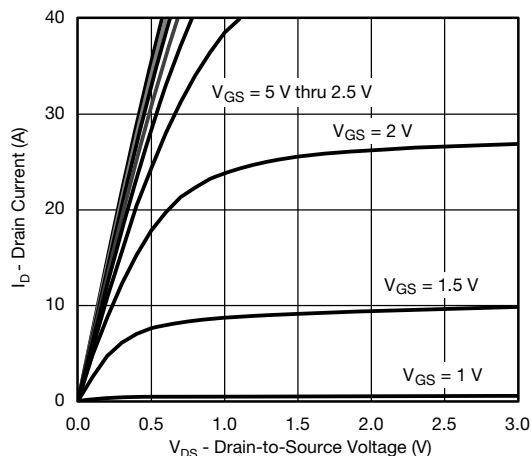
Notes

- a. Pulse test; pulse width $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$
b. Guaranteed by design, not subject to production testing

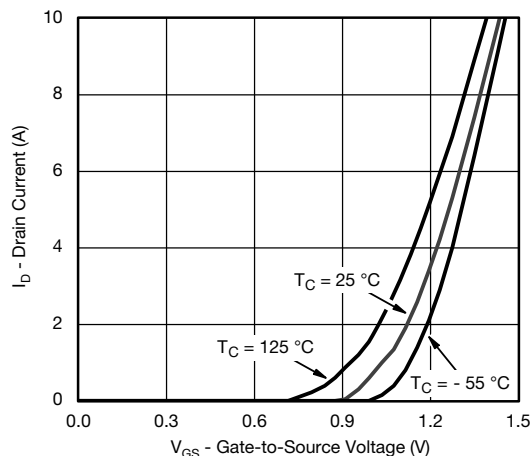
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



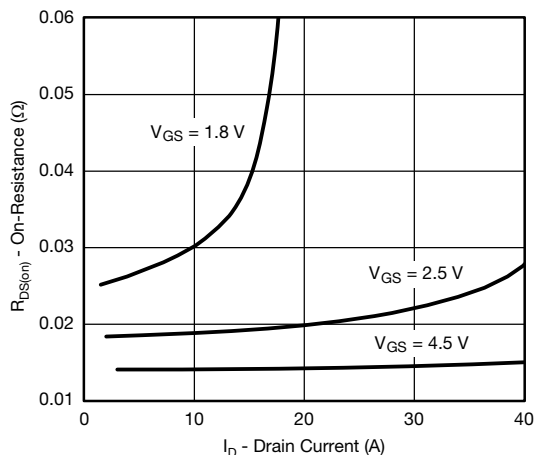
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



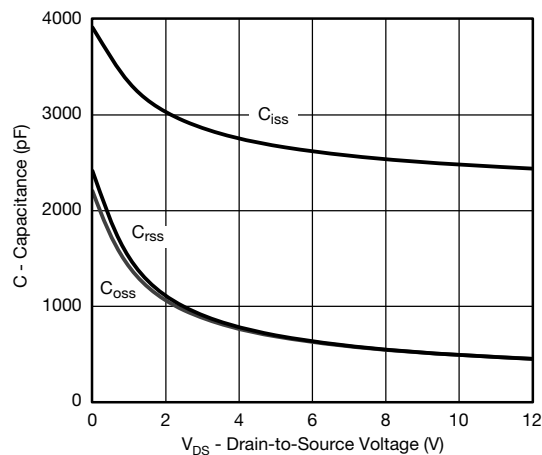
Output Characteristics



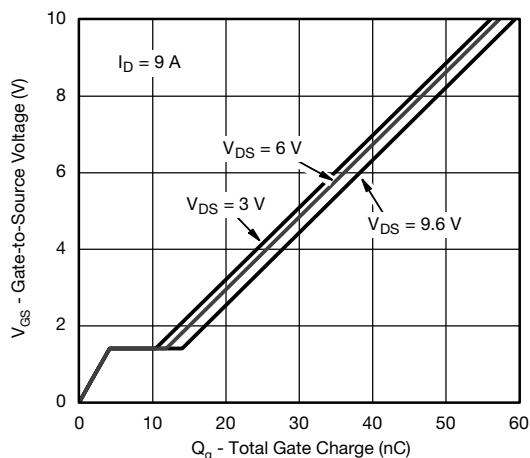
Transfer Characteristics



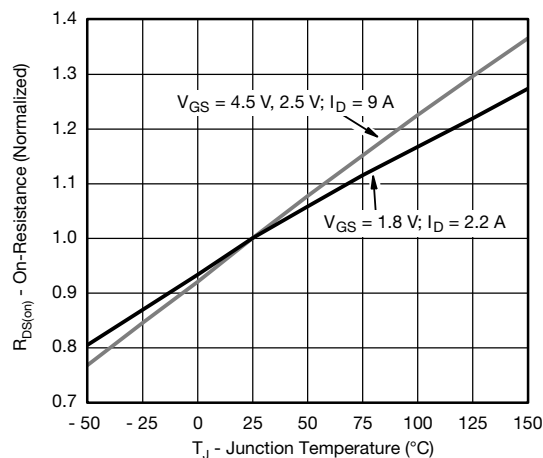
On-Resistance vs. Drain Current and Gate Voltage



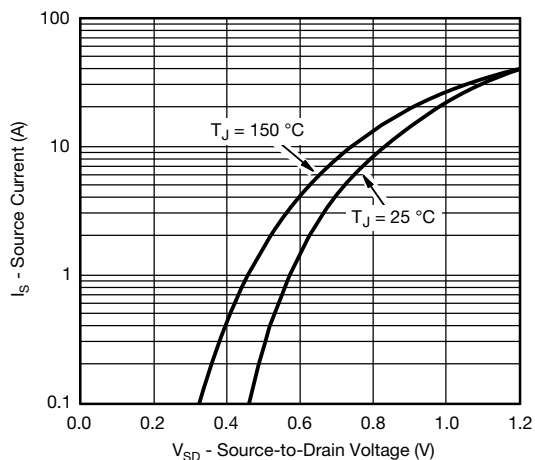
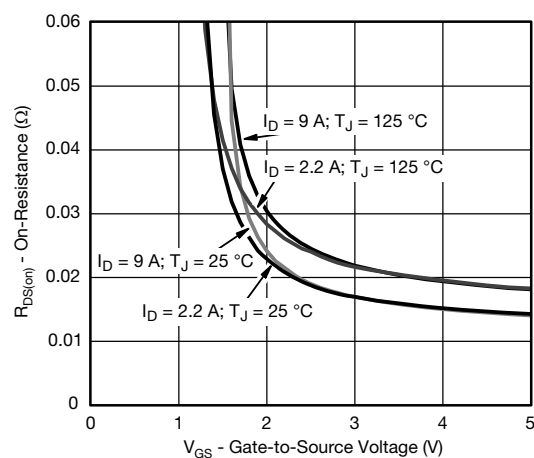
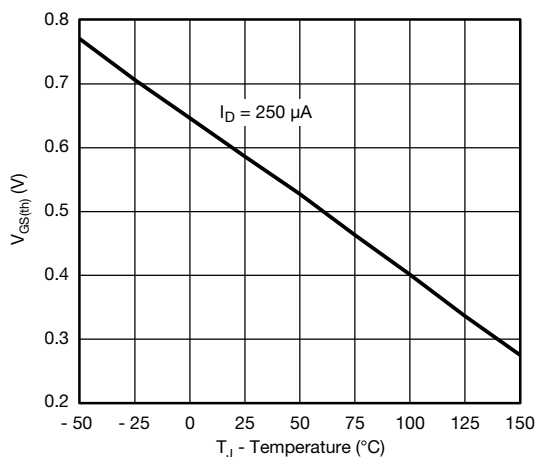
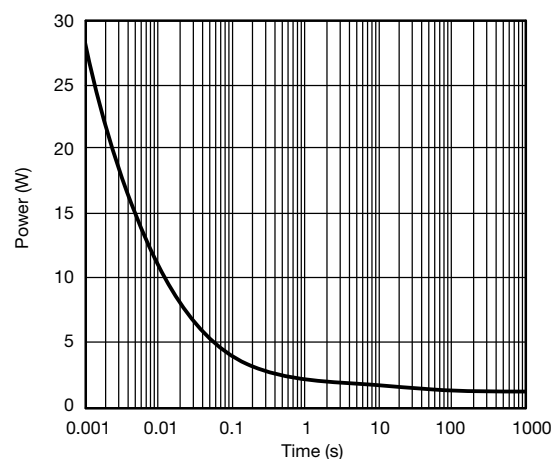
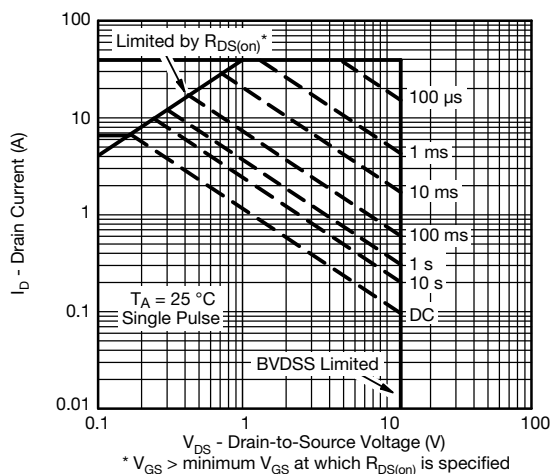
Capacitance

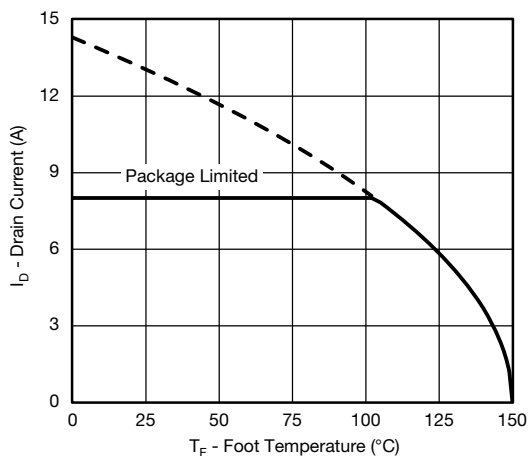
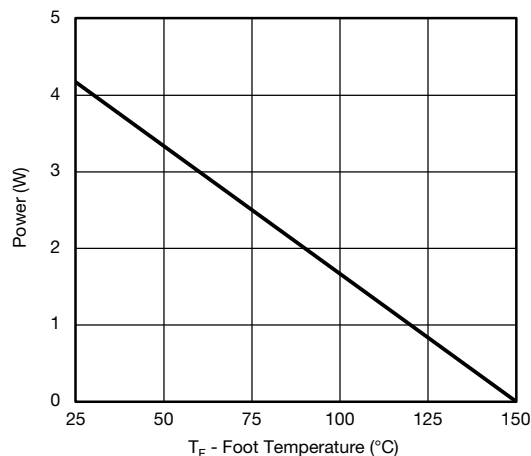


Gate Charge



On-Resistance vs. Junction Temperature

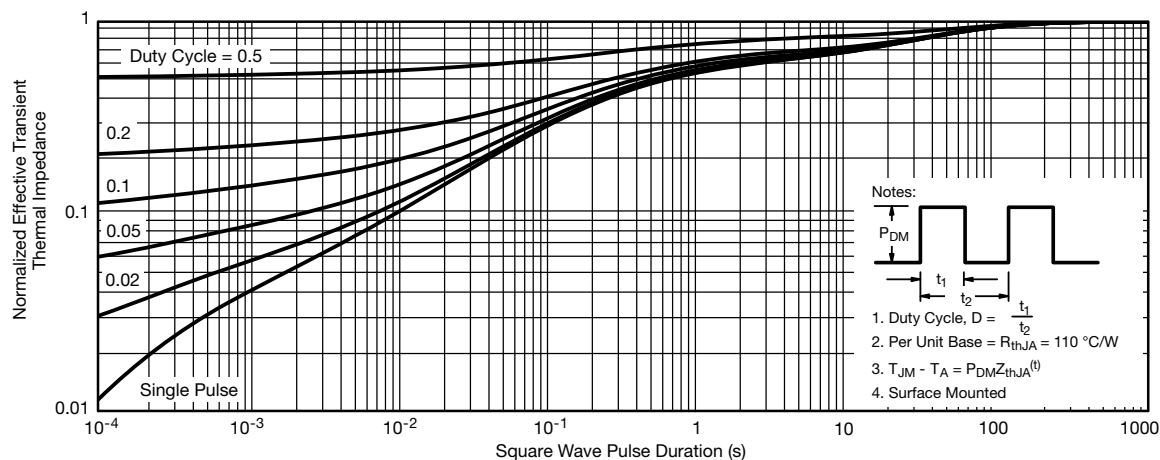
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

Source-Drain Diode Forward Voltage

On-Resistance vs. Gate-to-Source Voltage

Threshold Voltage

Single Pulse Power

Safe Operating Area

TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

Current Derating ^a

Power, Junction-to-Foot
Note

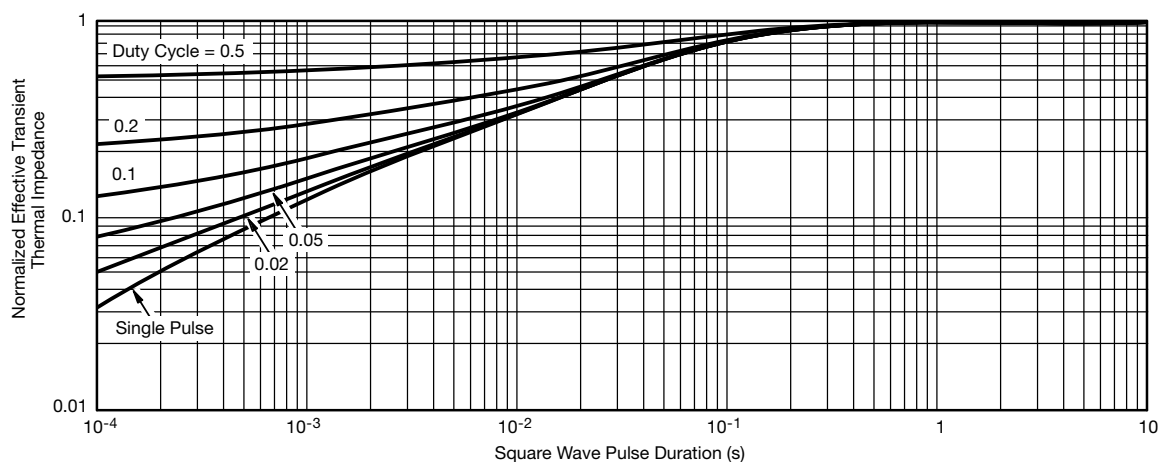
- a. The power dissipation P_D is based on T_J max. = 150 °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit



TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Foot

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TSOP: 5/6-LEAD

JEDEC Part Number: MO-193C



5-LEAD TSOP

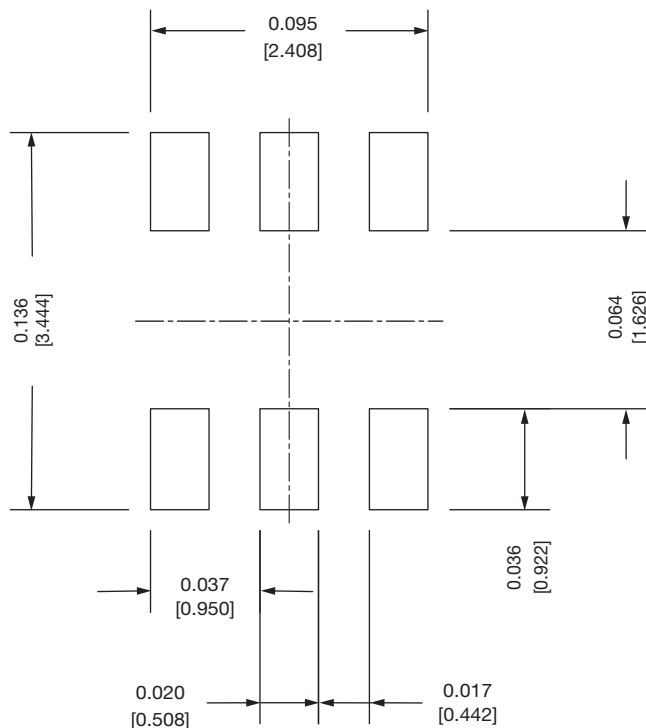
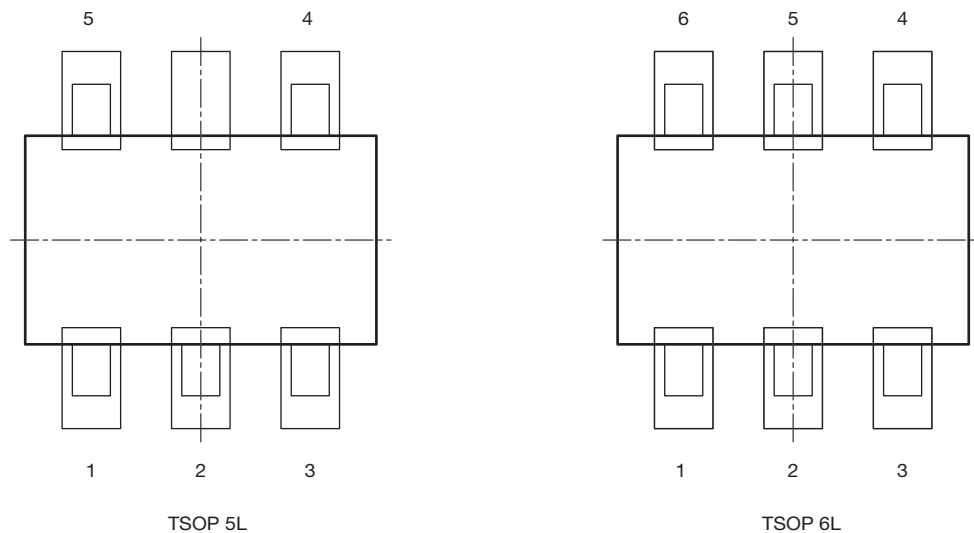


6-LEAD TSOP



	MILLIMETERS			INCHES		
Dim	Min	Nom	Max	Min	Nom	Max
A	0.91	-	1.10	0.036	-	0.043
A ₁	0.01	-	0.10	0.0004	-	0.004
A ₂	0.90	-	1.00	0.035	0.038	0.039
b	0.30	0.32	0.45	0.012	0.013	0.018
c	0.10	0.15	0.20	0.004	0.006	0.008
D	2.95	3.05	3.10	0.116	0.120	0.122
E	2.70	2.85	2.98	0.106	0.112	0.117
E ₁	1.55	1.65	1.70	0.061	0.065	0.067
e	0.95 BSC			0.0374 BSC		
e ₁	1.80	1.90	2.00	0.071	0.075	0.079
L	0.32	-	0.50	0.012	-	0.020
L ₁	0.60 Ref			0.024 Ref		
L ₂	0.25 BSC			0.010 BSC		
R	0.10	-	-	0.004	-	-
θ	0°	4°	8°	0°	4°	8°
θ ₁	7° Nom			7° Nom		
ECN: C-06593-Rev. I, 18-Dec-06						
DWG: 5540						

Recommended Land Pattern For TSOP-5L / TSOP-6L


Note

- All dimensions are in inches (millimeter)

ECN: C22-0860-Rev. B, 24-Oct-2022
DWG: 3010



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